Single 2-Input NAND Gate

The MC74HC1G00 is a high speed CMOS 2-input NAND gate fabricated with silicon gate CMOS technology.

The internal circuit is composed of multiple stages, including a buffer output which provides high noise immunity and stable output.

The MC74HC1G00 output drive current is 1/2 compared to MC74HC series.

Features

- High Speed: $t_{PD} = 7 \text{ ns} (Typ)$ at $V_{CC} = 5 \text{ V}$
- Low Power Dissipation: $I_{CC} = 1 \ \mu A (Max)$ at $T_A = 25^{\circ}C$
- High Noise Immunity
- Balanced Propagation Delays (t_{pLH} = t_{pHL})
- Symmetrical Output Impedance $(I_{OH} = I_{OL} = 2 \text{ mA})$
- Chip Complexity: < 100 FETs
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

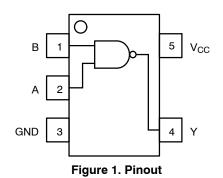




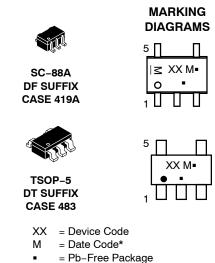
Figure 2. Logic Symbol

	PIN ASSIGNMENT					
1	В					
2	A					
3	GND					
4	Y					
5	V _{CC}					



ON Semiconductor®

www.onsemi.com



(Note: Microdot may be in either location) *Date Code orientation and/or position may vary depending upon manufacturing location.

> 5 1 SC-74A DBV SUFFIX CASE 318BQ



XXX = Specific Device Code M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

FUNCTION TABLE

Inp	uts	Output
Α	в	Y
L	L	Н
L	н	Н
н	L	Н
Н	Н	L

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data

MAXIMUM RATINGS

Symbol	Paramete	r	Value	Unit
V _{CC}	DC Supply Voltage	SC–88A (NLV), TSOP–5 SC–88A, SC–74A	-0.5 to +7.0 -0.5 to +6.5	V
V _{IN}	DC Input Voltage		–0.5 to V _{CC} +0.5	V
V _{OUT}	DC Output Voltage		–0.5 to V _{CC} +0.5	V
I _{IK}	DC Input Diode Current		±20	mA
I _{OK}	DC Output Diode Current		±20	mA
I _{OUT}	DC Output Source/Sink Current		±12.5	mA
$I_{CC} \text{ or } I_{GND}$	DC Supply Current per Supply Pin or Ground	l Pin	±25	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 S	econds	260	°C
TJ	Junction Temperature Under Bias		+150	°C
θ_{JA}	Thermal Resistance (Note 1)	SC70-5/SC-88A/SOT-353 SOT23-5/TSOP-5/SC59-5 SC-74A	659 555 555	°C/W
PD	Power Dissipation in Still Air at 85°C	SC70-5/SC-88A/SOT-353 SOT23-5/TSOP-5/SC59-5 SC-74A	190 225 225	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	1
V_{ESD}	ESD Withstand Voltage (Note 2)	Human Body Model Charged Device Model	2000 1000	V
ILATCHUP	Latchup Performance (Note 3)	SC-88A (NLV), SOT-23 SC-88A, SC-74A	±500 ±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 20 ounce copper trace with no air flow.
 HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to JESD22-C101-F. JEDEC recommends that ESD qualification to

EIA/JESD22–A115A (Machine Model) be discontinued per JEDEC/JEP172A. 3. Tested to EIA/JESD78 Class II.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Мах	Unit
V _{CC}	DC Supply Voltage	2.0	6.0	V
V _{IN}	DC Input Voltage	0.0	V _{CC}	V
V _{OUT}	DC Output Voltage	0.0	V _{CC}	V
T _A	Operating Temperature Range	-55	+125	°C
t _r , t _f	Input Rise and Fall Time SC–88A (NLV), TSOP–5 $V_{CC} = 2.0 \text{ V}$ $V_{CC} = 3.0 \text{ V}$ $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 6.0 \text{ V}$	0 0 0 0	1000 600 500 400	ns/V
	Input Rise and Fall Time $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 4.5 \text{ V to } 6.0 \text{ V}$	0 0 0 0	20 20 10 5	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

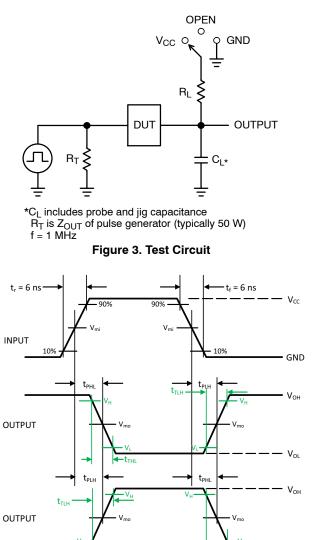
			V _{CC}	Т	A = 25°	C	-40°C ≤ 1	Γ _A ≤ 85°C	-55°C ≤ T	_A ≤ 125°C	
Symbol	Parameter	Test Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V _{IH}	High-Level Input Voltage		2.0 3.0 4.5 6.0	1.5 2.1 3.15 4.20	- - -		1.5 2.1 3.15 4.20	- - -	1.5 2.1 3.15 4.20	- - -	V
V _{IL}	Low-Level Input Voltage		2.0 3.0 4.5 6.0			0.5 0.9 1.35 1.80		0.5 0.9 1.35 1.80		0.5 0.9 1.35 1.80	V
V _{OH}	High-Level Output Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -20 \ \mu A$	2.0 3.0 4.5 6.0	1.9 2.9 4.4 5.9	2.0 3.0 4.5 6.0		1.9 2.9 4.4 5.9	- - -	1.9 2.9 4.4 5.9	- - -	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -2 \text{ mA}$ $I_{OH} = -2.6 \text{ mA}$	4.5 6.0	4.18 5.68	4.31 5.80		4.13 5.63		4.08 5.58		
V _{OL}	Low-Level Output Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 20 \ \mu A$	2.0 3.0 4.5 6.0		0.0 0.0 0.0 0.0	0.1 0.1 0.1 0.1		0.1 0.1 0.1 0.1		0.1 0.1 0.1 0.1	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 2 \text{ mA}$ $I_{OL} = 2.6 \text{ mA}$	4.5 6.0		0.17 0.18	0.26 0.26		0.33 0.33		0.40 0.40	
I _{IN}	Input Leakage Current	V _{IN} = 6.0 V or GND	6.0	-	-	±0.1 *	-	±1.0	-	±1.0	μΑ
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	6.0	-	-	1.0	-	10	-	40	μΑ

*Guaranteed by design.

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 6.0 \text{ ns}$)

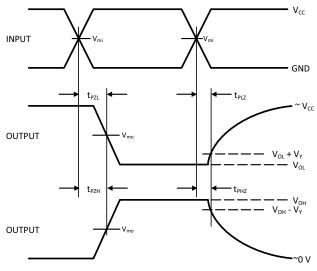
			Т	A = 25°	С	-40°C ≤ 1	Γ _A ≤ 85°C	–55°C ≤ T	_A ≤ 125°C	
Symbol	Parameter	Test Conditions	Min	Тур	Max	Min	Max	Min	Max	Unit
t _{PLH} ,	Propagation Delay,	$V_{CC} = 5.0 \text{ V}$ $C_{L} = 15 \text{ pF}$	-	3.5	15	-	20	_	25	ns
t _{PHL}	Input \tilde{A} or B to \overline{Y}	$ \begin{array}{ll} V_{CC} = 2.0 \ V & C_L = 50 \ pF \\ V_{CC} = 3.0 \ V & \\ V_{CC} = 4.5 \ V & \\ V_{CC} = 6.0 \ V & \end{array} $		20 11 8 7	100 27 20 17		125 35 25 21		155 90 35 26	
t _{TLH} ,	Output Transition	$V_{CC} = 5.0 \text{ V}$ $C_{L} = 15 \text{ pF}$	-	3	10	-	15	_	20	ns
t _{THL}	Time	$ \begin{array}{ll} V_{CC} = 2.0 \ V & C_L = 50 \ pF \\ V_{CC} = 3.0 \ V & \\ V_{CC} = 4.5 \ V & \\ V_{CC} = 6.0 \ V & \end{array} $	- - -	25 16 11 9	125 35 25 21		155 45 31 26		200 60 38 32	
C _{IN}	Input Capacitance		1	5	10	-	10	-	10	pF
						Typical @	25°C, V _{CC} :	= 5.0 V		
C _{PD}	Power Dissipation Ca	pacitance (Note 4)					10			pF

4. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no-load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.



Test	Switch Position	C _L , pF	R_{L}, Ω
t_{PLH} / t_{PHL}	Open		Х
t _{TLH} / t _{THL} (Note 5)	Open	See AC Characteristics Table	х
t _{PLZ} / t _{PZL}	V _{CC}	Table	1 k
t_{PHZ} / t_{PZH}	GND		1 k

X - Don't Care





VOL

			V _{mo} , V			
V_{CC}, V	V _{mi} , V	t _{PLH} , t _{PHL}	$t_{\text{PZL}}, t_{\text{PLZ}}, t_{\text{PZH}}, t_{\text{PHZ}}$	V _L , V	V _H , V	V _Y , V
3.0 to 3.6	V _{CC} /2	$(V_{OH} - V_{OL})/2$	V _{CC} /2	V _{OL} + 0.1 (V _{OH} – V _{OL})	V _{OL} + 0.9 (V _{OH} – V _{OL})	0.3
4.5 to 5.5	V _{CC} /2	(V _{OH} – V _{OL})/2	V _{CC} /2	V _{OL} + 0.1 (V _{OH} – V _{OL})	V _{OL} + 0.9 (V _{OH} – V _{OL})	0.3

5. t_{TLH} and t_{THL} are measured from 10% to 90% of (V_{OH} – V_{OL}), and 90% to 10% of (V_{OH} – V_{OL}), respectively.

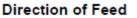
ORDERING INFORMATION

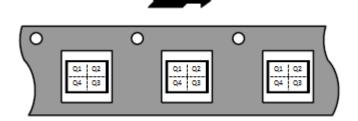
Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping [†]
MC74HC1G00DFT1G	SC-88A	H1	Q2	3000 / Tape & Reel
NLV74HC1G00DFT1G*	SC-88A	H1	Q2	3000 / Tape & Reel
MC74HC1G00DFT2G	SC-88A	H1	Q4	3000 / Tape & Reel
NLVHC1G00DFT2G*	SC-88A	H1	Q4	3000 / Tape & Reel
MC74HC1G00DTT1G	TSOP-5	H1	Q4	3000 / Tape & Reel
NLV74HC1G00DTT1G*	TSOP-5	H1	Q4	3000 / Tape & Reel
MC74HC1G00DBVT1G (In Development)	SC-74A	TBD	Q4	3000 / Tape & Reel

+For complete information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

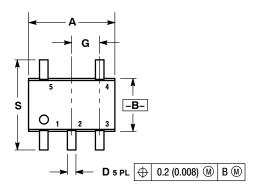
Pin 1 Orientation in Tape and Reel

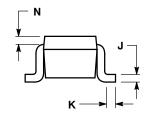




PACKAGE DIMENSIONS

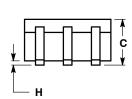
SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE L



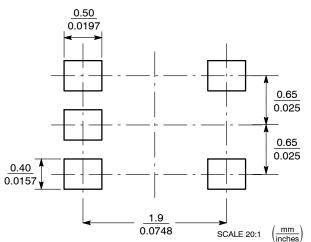


- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02. 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65 BSC	
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
Ν	0.008	REF	0.20	REF
S	0.079	0.087	2.00	2.20



SOLDER FOOTPRINT



PACKAGE DIMENSIONS

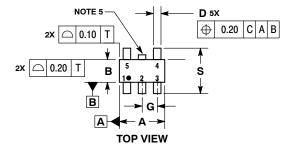
TSOP-5 **CASE 483 ISSUE M**

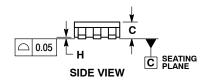
DETAIL Z

DETAIL Z

- NOTES:
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A.
 OPTIONAL CONSTRUCTION: AN ADDITIONAL
- 5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

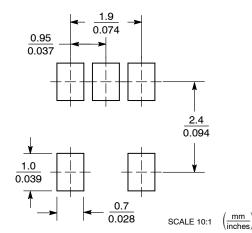
	MILLIN	MILLIMETERS				
DIM	MIN	MAX				
Α	2.85	3.15				
В	1.35	1.65				
С	0.90 1.10					
D	0.25	0.50				
G	0.95	BSC				
н	0.01	0.10				
J	0.10	0.26				
к	0.20	0.60				
Μ	0° 10°					
s	2.50	3.00				







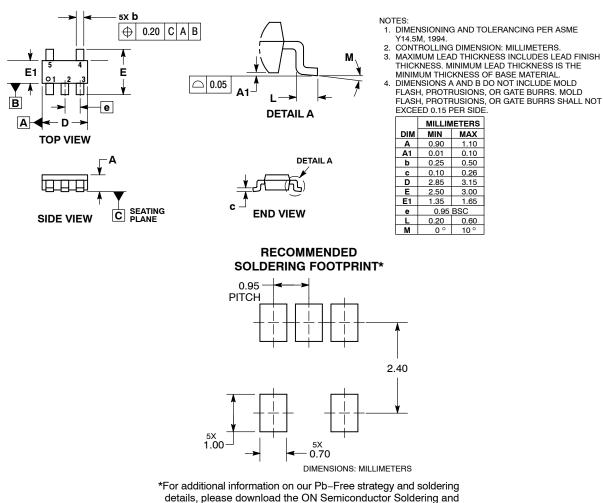
END VIEW



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

SC-74A CASE 318BQ ISSUE B



Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdt/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor dates sheets and/or application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights or others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products haranges, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Af

Phone: 421 33 790 2910

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: MC74HC1G00DFT1G MC74HC1G00DFT2G MC74HC1G00DTT1G